3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- $VCC = 2.5V \pm 0.2V$
- CMOS power levels (0.4μ W typ. static)
- · Rail-to-Rail output swing for increased noise margin
- · Available in TSSOP package

DRIVE FEATURES:

- · High Output Drivers: ±24mA
- · Suitable for heavy loads

APPLICATIONS:

- 3.3V high speed systems
- · 3.3V and lower voltage computing systems

DESCRIPTION:

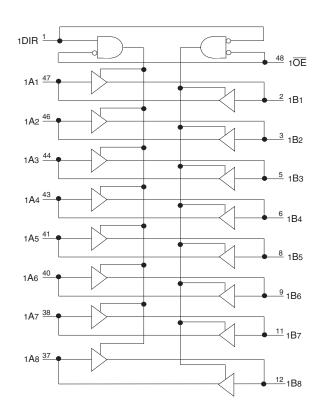
This 16-bit bus transceiver is built using advanced dual metal CMOS technology. The ALVCH16245 is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

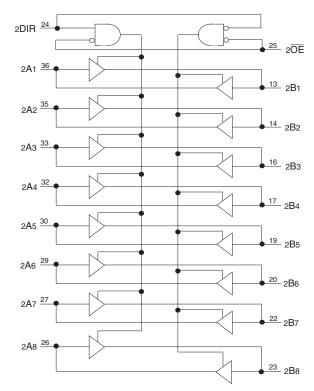
This device can be used as two 8-bit transceivers or one 16-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

The ALVCH16245 has been designed with a ± 24 mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH16245 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



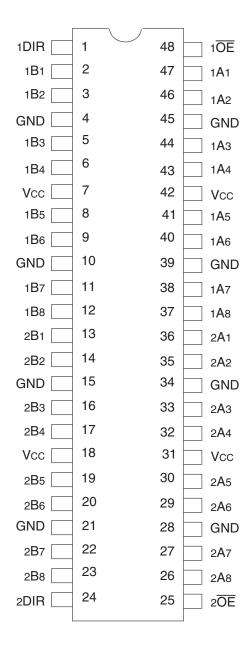


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INDUSTRIAL TEMPERATURE RANGE

AUGUST 2016

PIN CONFIGURATION



TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

| Symbol | Description | Max | Unit |
|----------------------|---|-----------------|------|
| VTERM ⁽²⁾ | Terminal Voltage with Respect to GND | -0.5 to +4.6 | ٧ |
| VTERM ⁽³⁾ | Terminal Voltage with Respect to GND | -0.5 to Vcc+0.5 | V |
| Tstg | Storage Temperature | -65 to +150 | °C |
| lout | DC Output Current | -50 to +50 | mA |
| lıĸ | Continuous Clamp Current, VI < 0 or VI > VCC | ±50 | mA |
| Іок | Continuous Clamp Current, Vo < 0 | -50 | mA |
| lcc lss | Continuous Current through each Vcc or GND | ±100 | mA |

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
 permanent damage to the device. This is a stress rating only and functional operation
 of the device at these or any other conditions above those indicated in the operational
 sections of this specification is not implied. Exposure to absolute maximum rating
 conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

| Symbol | Parameter ⁽¹⁾ | Conditions | Тур. | Max. | Unit |
|--------|--------------------------|------------|------|------|------|
| CIN | Input Capacitance | VIN = 0V | 5 | 7 | рF |
| Соит | Output Capacitance | Vout = 0V | 7 | 9 | рF |
| CI/O | I/O Port Capacitance | VIN = 0V | 7 | 9 | pF |

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

| Pin Names | Description | | |
|---|---|--|--|
| xŌĒ | xOE Output Enable Inputs (Active LOW) | | |
| DIR | Direction Control Inputs | | |
| x A x Side A Inputs or 3-State Outputs ⁽¹⁾ | | | |
| хВх | Side B Inputs or 3-State Outputs ⁽¹⁾ | | |

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)(1)

| Inp | outs | |
|-----|------|---------------------|
| хŌЕ | xDIR | Outputs |
| L | L | Bus B Data to Bus A |
| L | Н | Bus A Data to Bus B |
| Н | Х | High Z state |

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

| Symbol | Parameter | Test Con | ditions | Min. | Typ. ⁽¹⁾ | Max. | Unit |
|----------------------|---|-----------------------------------|--------------------|------|---------------------|------|------|
| VIH | Input HIGH Voltage Level | Vcc = 2.3V to 2.7V | | 1.7 | _ | _ | V |
| | | Vcc = 2.7V to 3.6V | | 2 | _ | _ | |
| VIL | Input LOW Voltage Level | Vcc = 2.3V to 2.7V | | T - | _ | 0.7 | V |
| | | Vcc = 2.7V to 3.6V | | _ | _ | 0.8 | |
| Iн | Input HIGH Current | Vcc = 3.6V | VI = VCC | _ | _ | ±5 | μA |
| lıL | Input LOW Current | Vcc = 3.6V | Vı = GND | _ | _ | ±5 | μA |
| lоzн | High Impedance Output Current | Vcc = 3.6V | Vo = Vcc | _ | _ | ±10 | μA |
| lozl | (3-State Output pins) | | Vo = GND | - | _ | ±10 | |
| Vik | Clamp Diode Voltage | Vcc = 2.3V, IIN = -18mA | | _ | -0.7 | -1.2 | V |
| Vн | Input Hysteresis | Vcc = 3.3V | | T - | 100 | _ | mV |
| ICCL ICCH ICCZ | Quiescent Power Supply Current | Vcc = 3.6V Vin = GND or Vcc | | _ | 0.1 | 40 | μΑ |
| Δlcc | Quiescent Power Supply Current Variation | One input at Vcc - 0.6V, other in | puts at Vcc or GND | _ | _ | 750 | μΑ |

NOTE:

BUS-HOLD CHARACTERISTICS

| Symbol | Parameter ⁽¹⁾ | Test Conditions | | Min. | Typ. ⁽²⁾ | Max. | Unit |
|--------|----------------------------------|-----------------|----------------|------|---------------------|------|------|
| Івнн | Bus-Hold Input Sustain Current | Vcc = 3V | VI = 2V | -75 | _ | | μΑ |
| IBHL | | | Vı = 0.8V | 75 | _ | 1 | |
| Івнн | Bus-Hold Input Sustain Current | Vcc = 2.3V | VI = 1.7V | -45 | _ | _ | μΑ |
| IBHL | | | VI = 0.7V | 45 | _ | _ | |
| Івнно | Bus-Hold Input Overdrive Current | Vcc = 3.6V | VI = 0 to 3.6V | _ | _ | ±500 | μΑ |
| Івньо | | | | | | | |

NOTES:

- 1. Pins with Bus-Hold are identified in the pin description.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.

^{1.} Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

| Symbol | Parameter | Test Con | ditions ⁽¹⁾ | Min. | Max. | Unit |
|--------|---------------------|--------------------|------------------------|---------|------|------|
| Voн | Output HIGH Voltage | Vcc = 2.3V to 3.6V | Iон = - 0.1mA | Vcc-0.2 | _ | V |
| | | Vcc = 2.3V | Iон = - 6mA | 2 | _ | |
| | | Vcc = 2.3V | Iон = - 12mA | 1.7 | _ | |
| | | Vcc = 2.7V | | 2.2 | _ | |
| | | Vcc = 3V | | 2.4 | _ | |
| | | Vcc = 3V | Iон = - 24mA | 2 | _ | |
| Vol | Output LOW Voltage | Vcc = 2.3V to 3.6V | IoL = 0.1mA | _ | 0.2 | V |
| | | Vcc = 2.3V | IoL = 6mA | _ | 0.4 | |
| | | | IoL = 12mA | _ | 0.7 | |
| | | Vcc = 2.7V | IoL = 12mA | _ | 0.4 | |
| | | Vcc = 3V | IoL = 24mA | _ | 0.55 | |

NOTE:

OPERATING CHARACTERISTICS, TA = 25°C

| | | | Vcc = 2.5V ± 0.2V | $Vcc = 3.3V \pm 0.3V$ | |
|--------|--|---------------------|-------------------|-----------------------|------|
| Symbol | Parameter | Test Conditions | Typical | Typical | Unit |
| CPD | Power Dissipation Capacitance Outputs enabled | CL = 0pF, f = 10Mhz | 22 | 29 | pF |
| CPD | Power Dissipation Capacitance Outputs disabled | | 4 | 5 | |

SWITCHING CHARACTERISTICS(1)

| | | Vcc = 2.5 | 5V ± 0.2V | Vcc = | 2.7V | Vcc = 3.3 | V ± 0.3V | |
|------------------|----------------------------|-----------|-----------|-------|------|-----------|----------|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| tPLH | Propagation Delay | 1 | 3.7 | _ | 3.6 | 1 | 3 | ns |
| t _{PHL} | xAx to xYx | | | | | | | |
| tpzh | Output Enable Time | 1 | 5.7 | _ | 5.4 | 1 | 4.4 | ns |
| tPZL | x OE to xYx | | | | | | | |
| tpHZ | Output Disable Time | 1 | 5.2 | _ | 4.6 | 1 | 4.1 | ns |
| tPLZ | x OE to xYx | | | | | | | |
| tsk(o) | Output Skew ⁽²⁾ | _ | _ | _ | _ | _ | 500 | ps |

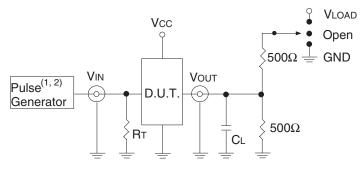
NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA = 40°C to + 85°C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = -40°C to + 85°C.

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

| Symbol | $Vcc^{(1)} = 3.3V \pm 0.3V$ | $Vcc^{(1)} = 2.7V$ | Vcc ⁽²⁾ =2.5V±0.2V | Unit |
|--------|-----------------------------|--------------------|-------------------------------|------|
| VLOAD | 6 | 6 | 2 x Vcc | ٧ |
| VIH | 2.7 | 2.7 | Vcc | V |
| VT | 1.5 | 1.5 | Vcc/2 | V |
| VLZ | 300 | 300 | 150 | mV |
| VHZ | 300 | 300 | 150 | mV |
| CL | 50 | 50 | 30 | pF |



Test Circuit for All Outputs ALVC Link

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

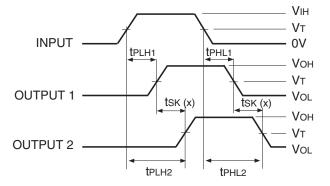
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

| Test | Switch |
|---|--------|
| Open Drain Disable Low Enable Low | VLOAD |
| Disable High Enable High | GND |
| All Other Tests | Open |

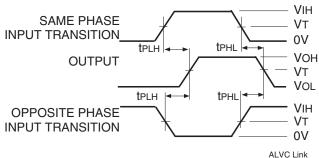


tsk(x) = |tPLH2 - tPLH| or tPHL2 - tPHL|

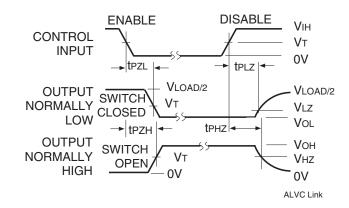
Output Skew - tsk(x)

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



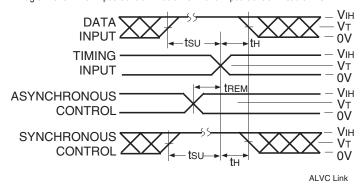
Propagation Delay



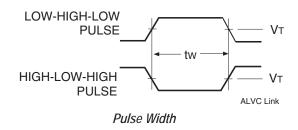
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

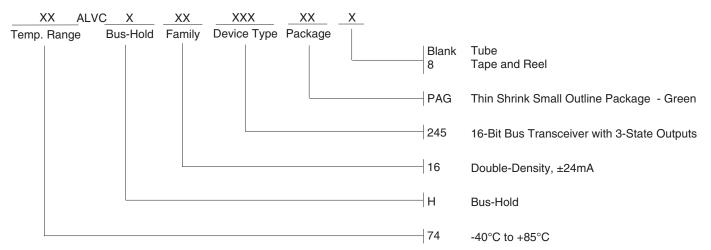


Set-up, Hold, and Release Times



5

ORDERING INFORMATION



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